



# Bipolar PNP Bare Die – BTP983

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## Part Description

The BTP983 is a silicon BJT transistor available in bare die form and well suited for use in High Voltage Driver applications..

## Key Parameters:

- VCBO = -300V
- VCEO = -300V
- VEBO = -7V
- hFE = 54-310 @ VCE = -10V, IC = -0.01A
- VCE(Sat) = -0.5V @ IC = -0.01A, IB = -1mA
- fT = 60 MHz @ VCE = -10V, IE = 0A
- COBO = 2pF @ VCB = -20V

## Features

Lower current 50mA version of MPSA92 with smaller die size

## Die Size (Unsawn)

390µm X 390µm, 15 Mils X 15 Mils

This is a shortform datasheet only

For the full datasheet

Please contact [sales@siliconsupplies.com](mailto:sales@siliconsupplies.com)

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